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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

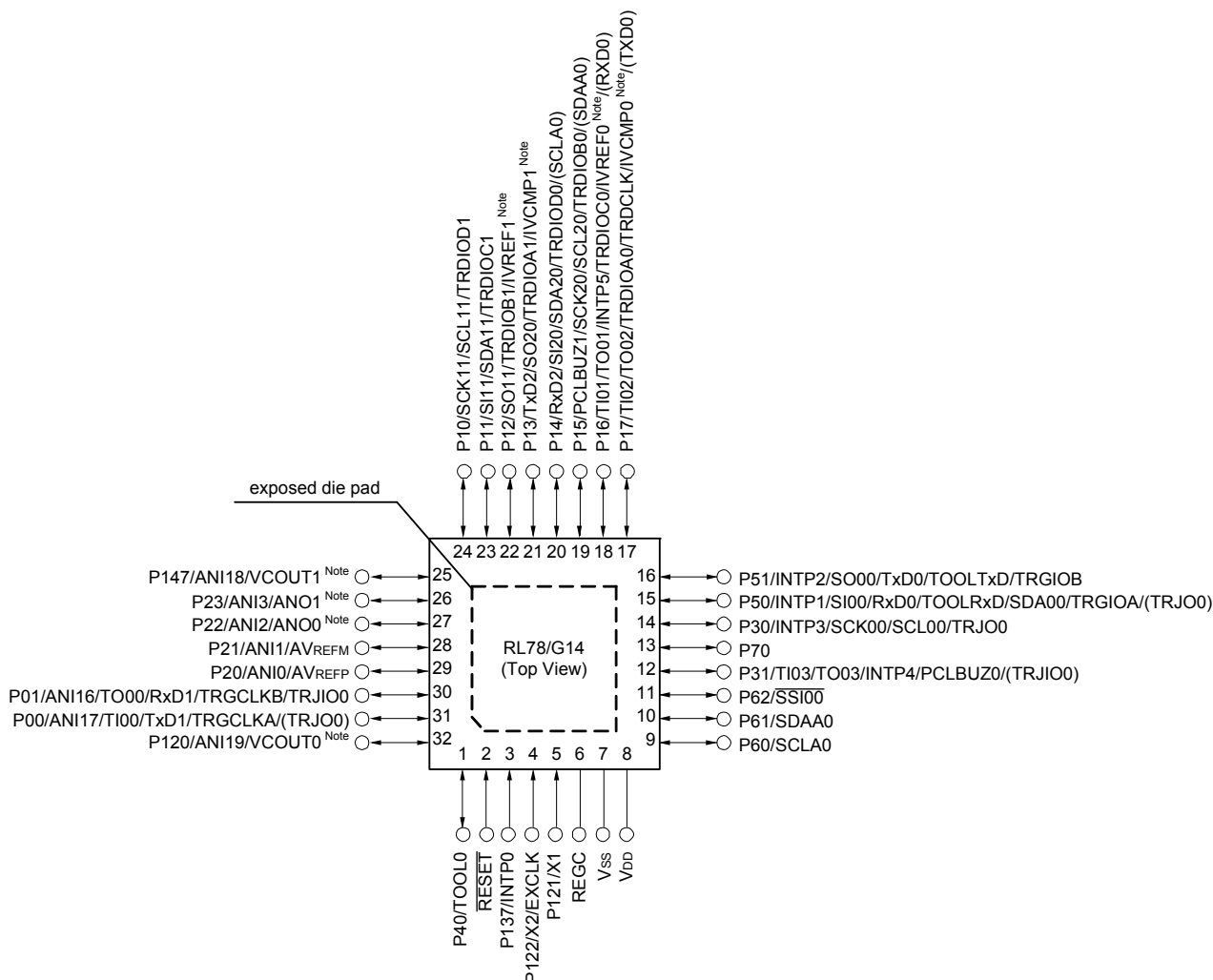
### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	RL78
Core Size	16-Bit
Speed	32MHz
Connectivity	CSI, I <sup>2</sup> C, LINbus, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	48
Program Memory Size	48KB (48K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	5.5K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 5.5V
Data Converters	A/D 12x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LFQFP (10x10)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f104ldafb-50">https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f104ldafb-50</a>

### 1.3.2 32-pin products

- 32-pin plastic HWQFN (5 × 5 mm, 0.5 mm pitch)



**Note** Mounted on the 96 KB or more code flash memory products.

**Caution** Connect the REGC pin to Vss pin via a capacitor (0.47 to 1  $\mu$ F).

**Remark 1.** For pin identification, see 1.4 Pin Identification.

**Remark 2.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).

**Remark 3.** It is recommended to connect an exposed die pad to Vss.

## 1.4 Pin Identification

ANI0 to ANI14,:	Analog input	RxD0 to RxD3:	Receive data
ANI16 to ANI20		SCK00, SCK01, SCK10,:	Serial clock input/output
ANO0, ANO1:	Analog output	SCK11, SCK20, SCK21,	
AVREFM:	A/D converter reference potential (– side) input	SCK30, SCK31	
AVREFP:	A/D converter reference potential (+ side) input	SCLA0, SCLA1,:	Serial clock input/output
EVDD0, EVDD1:	Power supply for port	SCL00, SCL01, SCL10, SCL11,:	Serial clock output
EVSS0, EVSS1:	Ground for port	SCL20, SCL21, SCL30,	
EXCLK:	External clock input (main system clock)	SCL31	
EXCLKS:	External clock input (subsystem clock)	SDAA0, SDAA1, SDA00,:	Serial data input/output
INTP0 to INTP11:	External interrupt input	SDA01, SDA10, SDA11,	
IVCMP0, IVCMP1:	Comparator input	SDA20, SDA21, SDA30,	
IVREF0, IVREF1:	Comparator reference input	SDA31	
KR0 to KR7:	Key return	SI00, SI01, SI10, SI11,:	Serial data input
P00 to P06:	Port 0	SI20, SI21, SI30, SI31	
P10 to P17:	Port 1	SO00, SO01, SO10,:	Serial data output
P20 to P27:	Port 2	SO11, SO20, SO21,	
P30, P31:	Port 3	SO30, SO31	
P40 to P47:	Port 4	$\overline{\text{SSI00}}$ :	Serial interface chip select input
P50 to P57:	Port 5	TI00 to TI03,:	Timer input
P60 to P67:	Port 6	TI10 to TI13	
P70 to P77:	Port 7	TO00 to TO03,:	Timer output
P80 to P87:	Port 8	TO10 to TO13, TRJ00	
P100 to P102:	Port 10	TOOL0:	Data input/output for tool
P110, P111:	Port 11	TOOLRxD, TOOLTxD:	Data input/output for external device
P120 to P124:	Port 12	TRDCLK, TRGCLKA,:	Timer external input clock
P130, P137:	Port 13	TRGCLKB	
P140 to P147:	Port 14	TRDIOA0, TRDIOB0,:	Timer input/output
P150 to P156:	Port 15	TRDIOC0, TRDIOD0,	
PCLBUZ0, PCLBUZ1:	Programmable clock output/buzzer output	TRDIOA1, TRDIOB1,	
REGC:	Regulator capacitance	TRDIOC1, TRDIOD1,	
$\overline{\text{RESET}}$ :	Reset	TRGIOA, TRGIOB, TRJIO0	
RTC1HZ:	Real-time clock correction clock (1 Hz) output	TxD0 to TxD3:	Transmit data
		VCOUT0, VCOUT1:	Comparator output
		VDD:	Power supply
		VSS:	Ground
		X1, X2:	Crystal oscillator (main system clock)
		XT1, XT2:	Crystal oscillator (subsystem clock)

(2/2)

Item		30-pin	32-pin	36-pin	40-pin
		R5F104Ax (x = F, G)	R5F104Bx (x = F, G)	R5F104Cx (x = F, G)	R5F104Ex (x = F to H)
Clock output/buzzer output		2	2	2	2
		[30-pin, 32-pin, 36-pin products] • 2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: $f_{MAIN} = 20$ MHz operation) [40-pin products] • 2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: $f_{MAIN} = 20$ MHz operation) • 256 Hz, 512 Hz, 1.024 kHz, 2.048 kHz, 4.096 kHz, 8.192 kHz, 16.384 kHz, 32.768 kHz (Subsystem clock: $f_{SUB} = 32.768$ kHz operation)			
8/10-bit resolution A/D converter		8 channels	8 channels	8 channels	9 channels
D/A converter		1 channel	2 channels		
Comparator		2 channels			
Serial interface		[30-pin, 32-pin products] • CSI: 1 channel/UART (UART supporting LIN-bus): 1 channel/simplified I <sup>2</sup> C: 1 channel • CSI: 1 channel/UART: 1 channel/simplified I <sup>2</sup> C: 1 channel • CSI: 1 channel/UART: 1 channel/simplified I <sup>2</sup> C: 1 channel [36-pin, 40-pin products] • CSI: 1 channel/UART (UART supporting LIN-bus): 1 channel/simplified I <sup>2</sup> C: 1 channel • CSI: 1 channel/UART: 1 channel/simplified I <sup>2</sup> C: 1 channel • CSI: 2 channels/UART: 1 channel/simplified I <sup>2</sup> C: 2 channels			
	I <sup>2</sup> C bus	1 channel	1 channel	1 channel	1 channel
Data transfer controller (DTC)		30 sources			31 sources
Event link controller (ELC)		Event input: 21 Event trigger output: 8	Event input: 21, Event trigger output: 9		Event input: 22 Event trigger output: 9
Vectored interrupt sources	Internal	24	24	24	24
	External	6	6	6	7
Key interrupt		—	—	—	4
Reset		• Reset by $\overline{RESET}$ pin • Internal reset by watchdog timer • Internal reset by power-on-reset • Internal reset by voltage detector • Internal reset by illegal instruction execution <sup>Note</sup> • Internal reset by RAM parity error • Internal reset by illegal-memory access			
Power-on-reset circuit		• Power-on-reset: 1.51 ±0.04 V ( $T_A = -40$ to +85°C) 1.51 ±0.06 V ( $T_A = -40$ to +105°C) • Power-down-reset: 1.50 ±0.04 V ( $T_A = -40$ to +85°C) 1.50 ±0.06 V ( $T_A = -40$ to +105°C)			
Voltage detector		1.63 V to 4.06 V (14 stages)			
On-chip debug function		Provided			
Power supply voltage		$V_{DD} = 1.6$ to 5.5 V ( $T_A = -40$ to +85°C) $V_{DD} = 2.4$ to 5.5 V ( $T_A = -40$ to +105°C)			
Operating ambient temperature		$T_A = -40$ to +85°C (A: Consumer applications, D: Industrial applications), $T_A = -40$ to +105°C (G: Industrial applications)			

**Note** The illegal instruction is generated when instruction code FFH is executed.  
 Reset by the illegal instruction execution not is issued by emulation with the in-circuit emulator or on-chip debug emulator.

[80-pin, 100-pin products (code flash memory 384 KB to 512 KB)]

**Caution** This outline describes the functions at the time when Peripheral I/O redirection register 0, 1 (PIOR0, 1) are set to 00H.

(1/2)

Item		80-pin	100-pin
		R5F104Mx (x = K, L)	R5F104Px (x = K, L)
Code flash memory (KB)		384 to 512	384 to 512
Data flash memory (KB)		8	8
RAM (KB)		32 to 48 Note	32 to 48 Note
Address space		1 MB	
Main system clock	High-speed system clock	X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (high-speed main) mode: 1 to 20 MHz ( $V_{DD} = 2.7$ to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz ( $V_{DD} = 2.4$ to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz ( $V_{DD} = 1.8$ to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz ( $V_{DD} = 1.6$ to 5.5 V)	
	High-speed on-chip oscillator clock ( $f_{IH}$ )	HS (high-speed main) mode: 1 to 32 MHz ( $V_{DD} = 2.7$ to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz ( $V_{DD} = 2.4$ to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz ( $V_{DD} = 1.8$ to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz ( $V_{DD} = 1.6$ to 5.5 V)	
Subsystem clock		XT1 (crystal) oscillation, external subsystem clock input (EXCLKS) 32.768 kHz	
Low-speed on-chip oscillator clock		15 kHz (TYP.): $V_{DD} = 1.6$ to 5.5 V	
General-purpose register		8 bits $\times$ 32 registers (8 bits $\times$ 8 registers $\times$ 4 banks)	
Minimum instruction execution time		0.03125 $\mu$ s (High-speed on-chip oscillator clock: $f_{IH} = 32$ MHz operation)	
		0.05 $\mu$ s (High-speed system clock: $f_{MX} = 20$ MHz operation)	
		30.5 $\mu$ s (Subsystem clock: $f_{SUB} = 32.768$ kHz operation)	
Instruction set		<ul style="list-style-type: none"> <li>• Data transfer (8/16 bits)</li> <li>• Adder and subtractor/logical operation (8/16 bits)</li> <li>• Multiplication (8 bits <math>\times</math> 8 bits, 16 bits <math>\times</math> 16 bits), Division (16 bits <math>\div</math> 16 bits, 32 bits <math>\div</math> 32 bits)</li> <li>• Multiplication and Accumulation (16 bits <math>\times</math> 16 bits + 32 bits)</li> <li>• Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc.</li> </ul>	
I/O port	Total	74	92
	CMOS I/O	64	82
	CMOS input	5	5
	CMOS output	1	1
	N-ch open-drain I/O (6 V tolerance)	4	4
Timer	16-bit timer	12 channels (TAU: 8 channels, Timer RJ: 1 channel, Timer RD: 2 channels, Timer RG: 1 channel)	
	Watchdog timer	1 channel	
	Real-time clock (RTC)	1 channel	
	12-bit interval timer	1 channel	
	Timer output	Timer outputs: 18 channels PWM outputs: 12 channels	
	RTC output	1 • 1 Hz (subsystem clock: $f_{SUB} = 32.768$ kHz)	

**Note** In the case of the 48 KB, this is about 47 KB when the self-programming function and data flash function are used (For details, see **CHAPTER 3** in the RL78/G14 User's Manual).

## (1) Flash ROM: 16 to 64 KB of 30- to 64-pin products

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = 0 V)(2/2)

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit			
Supply current Note 1	I <sub>DD2</sub> Note 2	HALT mode	HS (high-speed main) mode Note 7	f <sub>HOCO</sub> = 64 MHz, f <sub>IH</sub> = 32 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.80	3.09	mA			
					V <sub>DD</sub> = 3.0 V		0.80	3.09				
				f <sub>HOCO</sub> = 32 MHz, f <sub>IH</sub> = 32 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.49	2.40				
					V <sub>DD</sub> = 3.0 V		0.49	2.40				
				f <sub>HOCO</sub> = 48 MHz, f <sub>IH</sub> = 24 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.62	2.40				
					V <sub>DD</sub> = 3.0 V		0.62	2.40				
				f <sub>HOCO</sub> = 24 MHz, f <sub>IH</sub> = 24 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.4	1.83				
					V <sub>DD</sub> = 3.0 V		0.4	1.83				
				f <sub>HOCO</sub> = 16 MHz, f <sub>IH</sub> = 16 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.37	1.38				
					V <sub>DD</sub> = 3.0 V		0.37	1.38				
			LS (low-speed main) mode Note 7	f <sub>HOCO</sub> = 8 MHz, f <sub>IH</sub> = 8 MHz Note 4	V <sub>DD</sub> = 3.0 V		260	710	μA			
					V <sub>DD</sub> = 2.0 V		260	710				
			LV (low-voltage main) mode Note 7	f <sub>HOCO</sub> = 4 MHz, f <sub>IH</sub> = 4 MHz Note 4	V <sub>DD</sub> = 3.0 V		420	700	μA			
					V <sub>DD</sub> = 2.0 V		420	700				
			HS (high-speed main) mode Note 7	f <sub>MX</sub> = 20 MHz Note 3, V <sub>DD</sub> = 5.0 V	Square wave input		0.28	1.55	mA			
					Resonator connection		0.40	1.74				
					f <sub>MX</sub> = 20 MHz Note 3, V <sub>DD</sub> = 3.0 V	Square wave input		0.28		1.55		
						Resonator connection		0.40		1.74		
					f <sub>MX</sub> = 10 MHz Note 3, V <sub>DD</sub> = 5.0 V	Square wave input		0.19		0.86		
						Resonator connection		0.25		0.93		
					f <sub>MX</sub> = 10 MHz Note 3, V <sub>DD</sub> = 3.0 V	Square wave input		0.19		0.86		
						Resonator connection		0.25		0.93		
					LS (low-speed main) mode Note 7	f <sub>MX</sub> = 8 MHz Note 3, V <sub>DD</sub> = 3.0 V	Square wave input			95	550	μA
							Resonator connection			140	590	
			f <sub>MX</sub> = 8 MHz Note 3, V <sub>DD</sub> = 2.0 V	Square wave input			95	550				
				Resonator connection			140	590				
			Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz Note 5, T <sub>A</sub> = -40°C	Square wave input		0.25	0.57	μA			
					Resonator connection		0.44	0.76				
				f <sub>SUB</sub> = 32.768 kHz Note 5, T <sub>A</sub> = +25°C	Square wave input		0.30	0.57				
					Resonator connection		0.49	0.76				
				f <sub>SUB</sub> = 32.768 kHz Note 5, T <sub>A</sub> = +50°C	Square wave input		0.36	1.17				
					Resonator connection		0.59	1.36				
				f <sub>SUB</sub> = 32.768 kHz Note 5, T <sub>A</sub> = +70°C	Square wave input		0.49	1.97				
					Resonator connection		0.72	2.16				
				f <sub>SUB</sub> = 32.768 kHz Note 5, T <sub>A</sub> = +85°C	Square wave input		0.97	3.37				
					Resonator connection		1.16	3.56				
			I <sub>DD3</sub> Note 6	STOP mode Note 8	T <sub>A</sub> = -40°C					0.18	0.51	μA
					T <sub>A</sub> = +25°C					0.24	0.51	
					T <sub>A</sub> = +50°C					0.29	1.10	
					T <sub>A</sub> = +70°C					0.41	1.90	
					T <sub>A</sub> = +85°C					0.90	3.30	

(Notes and Remarks are listed on the next page.)

- Note 1.** Total current flowing into V<sub>DD</sub> and EV<sub>DD0</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub>, EV<sub>DD0</sub> or V<sub>SS</sub>, EV<sub>SS0</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
- Note 2.** During HALT instruction execution by flash memory.
- Note 3.** When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 4.** When high-speed system clock and subsystem clock are stopped.
- Note 5.** When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
- Note 6.** Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
- Note 7.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
- |                             |   |
|-----------------------------|---|
| HS (high-speed main) mode:  | 2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 32 MHz |
|                             | 2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 16 MHz |
| LS (low-speed main) mode:   | 1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 8 MHz  |
| LV (low-voltage main) mode: | 1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 4 MHz  |
- Note 8.** Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.
- Remark 1.** f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
- Remark 2.** f<sub>HOCO</sub>: High-speed on-chip oscillator clock frequency (64 MHz max.)
- Remark 3.** f<sub>IH</sub>: High-speed on-chip oscillator clock frequency (32 MHz max.)
- Remark 4.** f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 5.** Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is T<sub>A</sub> = 25°C

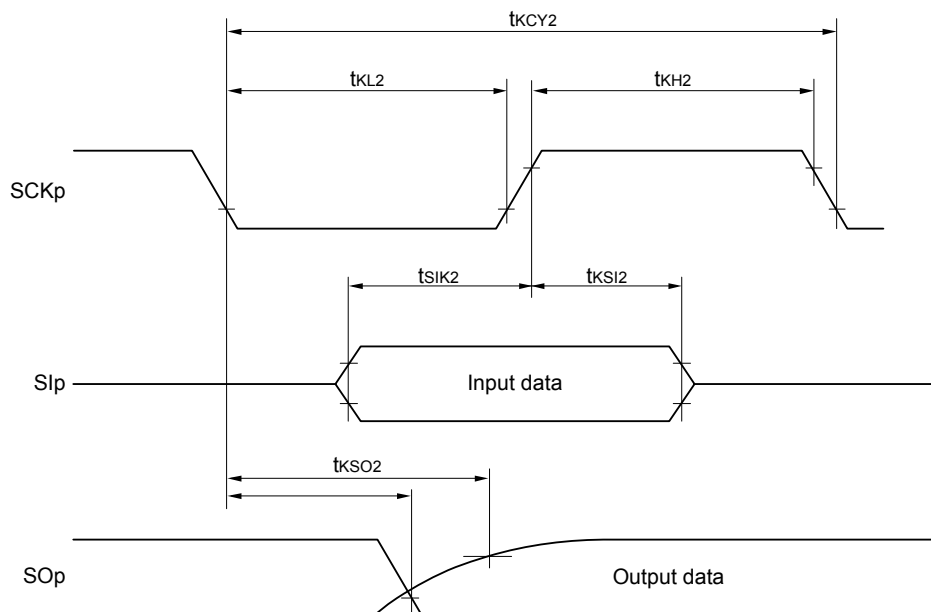
**(4) Peripheral Functions (Common to all products)****(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Low-speed on-chip oscillator operating current	IFIL Note 1				0.20		μA
RTC operating current	IRTC Notes 1, 2, 3				0.02		μA
12-bit interval timer operating current	IIIT Notes 1, 2, 4				0.02		μA
Watchdog timer operating current	IWDOT Notes 1, 2, 5	fIL = 15 kHz			0.22		μA
A/D converter operating current	IADC Notes 1, 6	When conversion at maximum speed	Normal mode, AVREFP = VDD = 5.0 V		1.3	1.7	mA
			Low voltage mode, AVREFP = VDD = 3.0 V		0.5	0.7	mA
A/D converter reference voltage current	IADREF Note 1				75.0		μA
Temperature sensor operating current	ITMPS Note 1				75.0		μA
D/A converter operating current	IDAC Notes 1, 11, 13	Per D/A converter channel				1.5	mA
Comparator operating current	ICMP Notes 1, 12, 13	VDD = 5.0 V, Regulator output voltage = 2.1 V	Window mode		12.5		μA
			Comparator high-speed mode		6.5		μA
			Comparator low-speed mode		1.7		μA
		VDD = 5.0 V, Regulator output voltage = 1.8 V	Window mode		8.0		μA
			Comparator high-speed mode		4.0		μA
			Comparator low-speed mode		1.3		μA
LVD operating current	ILVD Notes 1, 7				0.08		μA
Self-programming operating current	IFSP Notes 1, 9				2.50	12.20	mA
BGO operating current	IBGO Notes 1, 8				2.50	12.20	mA
SNOOZE operating current	ISNOZ Note 1	ADC operation	The mode is performed Note 10		0.50	0.60	mA
			The A/D conversion operations are performed, Low voltage mode, AVREFP = VDD = 3.0 V		1.20	1.44	
		CSI/UART operation			0.70	0.84	
		DTC operation			3.10		

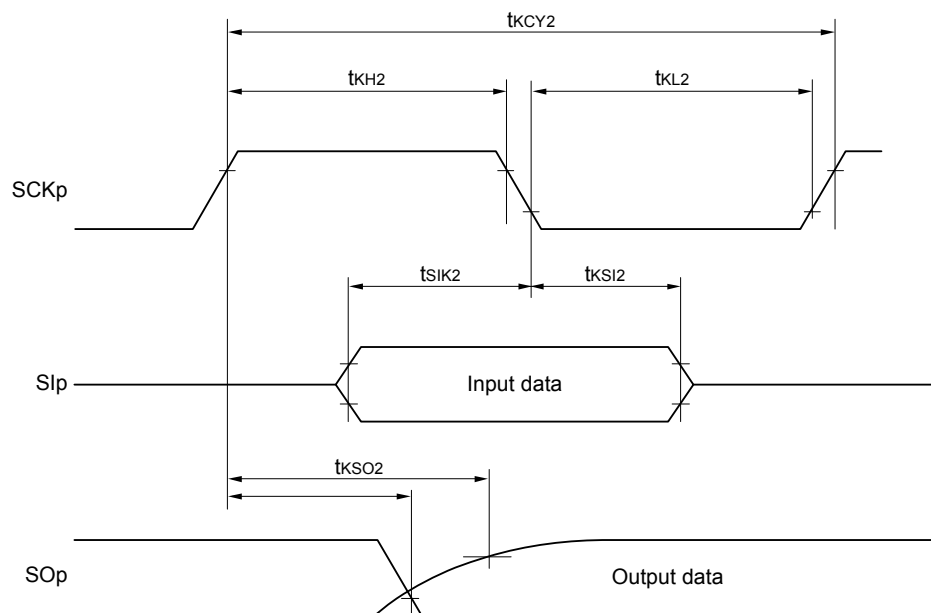
**Note 1.** Current flowing to VDD.**Note 2.** When high speed on-chip oscillator and high-speed system clock are stopped.**Note 3.** Current flowing only to the real-time clock (RTC) (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and IRTC, when the real-time clock operates in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, IFIL should be added. IDD2 subsystem clock operation includes the operational current of the real-time clock.**Note 4.** Current flowing only to the 12-bit interval timer (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and IIIT, when the 12-bit interval timer operates in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, IFIL should be added.



**CSI mode serial transfer timing (slave mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)**



**CSI mode serial transfer timing (slave mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



**Remark 1.** p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3),  
g: PIM and POM number (g = 0, 1, 3 to 5, 14)

**Remark 2.** CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.  
Also, communication at different potential cannot be performed during clock synchronous serial communication with the slave select function.

## 2.6 Analog Characteristics

### 2.6.1 A/D converter characteristics

#### Classification of A/D converter characteristics

Input channel	Reference Voltage	Reference voltage (+) = AV <sub>REFP</sub> Reference voltage (-) = AV <sub>REFM</sub>	Reference voltage (+) = V <sub>DD</sub> Reference voltage (-) = V <sub>SS</sub>	Reference voltage (+) = V <sub>BGR</sub> Reference voltage (-) = AV <sub>REFM</sub>
ANI0 to ANI14		Refer to 2.6.1 (1).	Refer to 2.6.1 (3).	Refer to 2.6.1 (4).
ANI16 to ANI20		Refer to 2.6.1 (2).		
Internal reference voltage Temperature sensor output voltage		Refer to 2.6.1 (1).		—

(1) When reference voltage (+) = AV<sub>REFP</sub>/ANI0 (ADREFP1 = 0, ADREFP0 = 1), reference voltage (-) = AV<sub>REFM</sub>/ANI1 (ADREFM = 1), target pin: ANI2 to ANI14, internal reference voltage, and temperature sensor output voltage

(TA = -40 to +85°C, 1.6 V ≤ AV<sub>REFP</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V, Reference voltage (+) = AV<sub>REFP</sub>, Reference voltage (-) = AV<sub>REFM</sub> = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	RES		8		10	bit
Overall error Note 1	AINL	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> Note 3	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V	1.2	±3.5	LSB
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V Note 4	1.2	±7.0	LSB
Conversion time	t <sub>CONV</sub>	10-bit resolution Target pin: ANI2 to ANI14	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.125	39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.1875	39	μs
			1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V	17	39	μs
			1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	57	95	μs
		10-bit resolution Target pin: Internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode)	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.375	39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.5625	39	μs
			2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	17	39	μs
Zero-scale error Notes 1, 2	E <sub>ZS</sub>	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> Note 3	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±0.25	%FSR
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V Note 4		±0.50	%FSR
Full-scale error Notes 1, 2	E <sub>FS</sub>	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> Note 3	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±0.25	%FSR
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V Note 4		±0.50	%FSR
Integral linearity error Note 1	ILE	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> Note 3	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±2.5	LSB
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V Note 4		±5.0	LSB
Differential linearity error Note 1	DLE	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> Note 3	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±1.5	LSB
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V Note 4		±2.0	LSB
Analog input voltage	V <sub>AIN</sub>	ANI2 to ANI14	0		AV <sub>REFP</sub>	V
		Internal reference voltage (2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode)			V <sub>BGR</sub> Note 5	V
		Temperature sensor output voltage (2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode)			V <sub>TMPS25</sub> Note 5	V

**Note 1.** Excludes quantization error (±1/2 LSB).

**Note 2.** This value is indicated as a ratio (%FSR) to the full-scale value.

**Note 3.** When AV<sub>REFP</sub> < V<sub>DD</sub>, the MAX. values are as follows.

Overall error: Add ±1.0 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Zero-scale error/Full-scale error: Add ±0.05%FSR to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Integral linearity error/ Differential linearity error: Add ±0.5 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

**Note 4.** Values when the conversion time is set to 57 μs (min.) and 95 μs (max.).

**Note 5.** Refer to 2.6.2 Temperature sensor characteristics/internal reference voltage characteristic.

- (4) When reference voltage (+) = Internal reference voltage (ADREFP1 = 1, ADREFP0 = 0), reference voltage (-) = AVREFM/ANI1 (ADREFM = 1), target pin: ANI0, ANI2 to ANI14, ANI16 to ANI20

(TA = -40 to +85°C, 2.4 V ≤ VDD ≤ 5.5 V, 1.6 V ≤ EVDD = EVDD1 ≤ VDD, VSS = EVSS0 = EVSS1 = 0 V, Reference voltage (+) = VBGR <sup>Note 3</sup>, Reference voltage (-) = AVREFM = 0 V <sup>Note 4</sup>, HS (high-speed main) mode)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8			bit
Conversion time	tCONV	8-bit resolution	2.4 V ≤ VDD ≤ 5.5 V	17		39	μs
Zero-scale error <sup>Notes 1, 2</sup>	Ezs	8-bit resolution	2.4 V ≤ VDD ≤ 5.5 V			±0.60	% FSR
Integral linearity error <sup>Note 1</sup>	ILE	8-bit resolution	2.4 V ≤ VDD ≤ 5.5 V			±2.0	LSB
Differential linearity error <sup>Note 1</sup>	DLE	8-bit resolution	2.4 V ≤ VDD ≤ 5.5 V			±1.0	LSB
Analog input voltage	VAIN			0		VBGR <sup>Note 3</sup>	V

**Note 1.** Excludes quantization error (±1/2 LSB).

**Note 2.** This value is indicated as a ratio (% FSR) to the full-scale value.

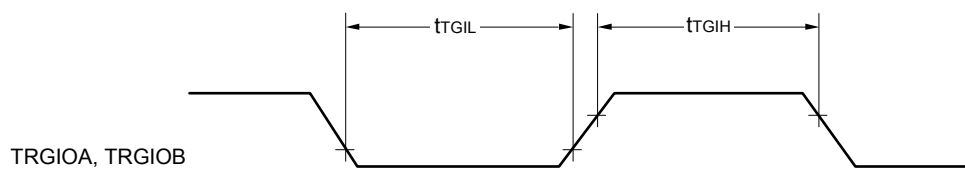
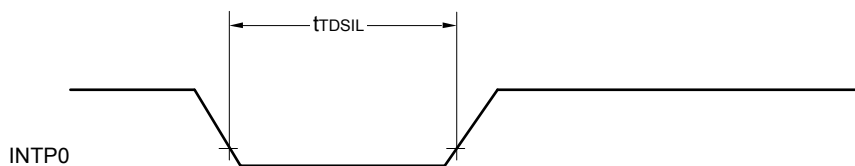
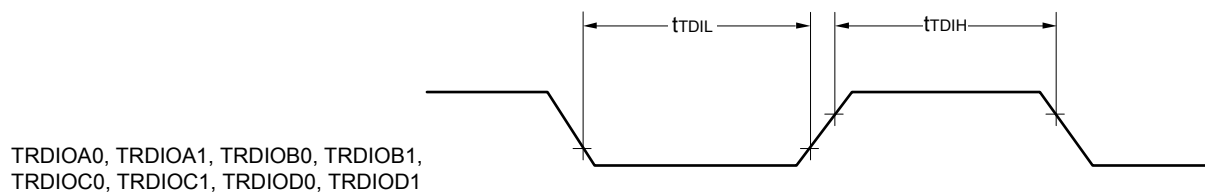
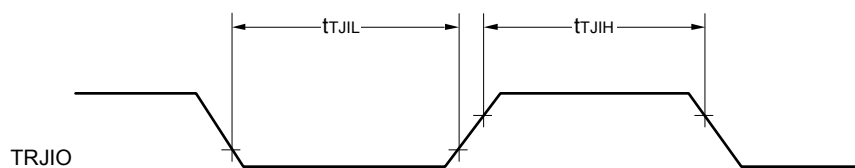
**Note 3.** Refer to 2.6.2 Temperature sensor characteristics/internal reference voltage characteristic.

**Note 4.** When reference voltage (-) = VSS, the MAX. values are as follows.

Zero-scale error: Add ±0.35%FSR to the MAX. value when reference voltage (-) = AVREFM.

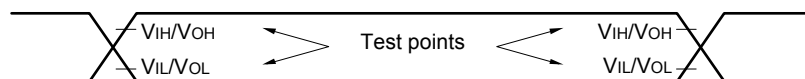
Integral linearity error: Add ±0.5 LSB to the MAX. value when reference voltage (-) = AVREFM.

Differential linearity error: Add ±0.2 LSB to the MAX. value when reference voltage (-) = AVREFM.



### 3.5 Peripheral Functions Characteristics

#### AC Timing Test Points



#### 3.5.1 Serial array unit

##### (1) During communication at same potential (UART mode)

( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EVDD0} = \text{EVDD1} \leq 5.5\text{ V}$ ,  $\text{Vss} = \text{EVss0} = \text{EVss1} = 0\text{ V}$ )

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
Transfer rate Note 1		$2.4\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$		$f_{\text{MCK}}/12$ Note 2	bps
		Theoretical value of the maximum transfer rate $f_{\text{MCK}} = f_{\text{CLK}}$ Note 3		2.6	Mbps

**Note 1.** Transfer rate in the SNOOZE mode is 4800 bps only.

However, the SNOOZE mode cannot be used when  $\text{FRQSEL4} = 1$ .

**Note 2.** The following conditions are required for low voltage interface when  $\text{EVDD0} < V_{\text{DD}}$ .

$2.4\text{ V} \leq \text{EVDD0} < 2.7\text{ V}$ : MAX. 1.3 Mbps

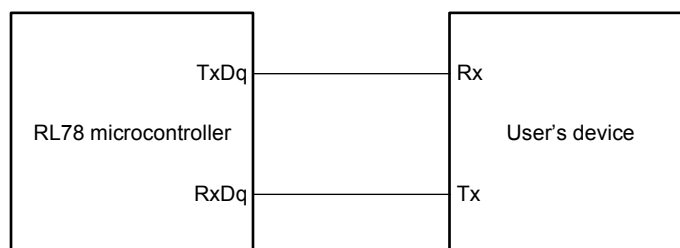
**Note 3.** The maximum operating frequencies of the CPU/peripheral hardware clock ( $f_{\text{CLK}}$ ) are:

HS (high-speed main) mode: 32 MHz ( $2.7\text{ V} \leq V_{\text{DD}} \leq 5.5\text{ V}$ )

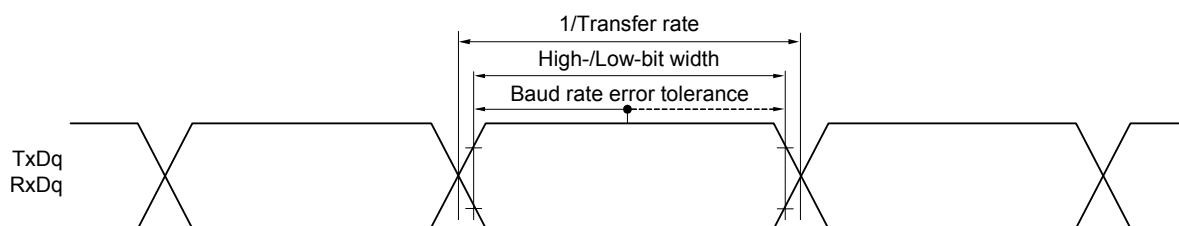
16 MHz ( $2.4\text{ V} \leq V_{\text{DD}} \leq 5.5\text{ V}$ )

**Caution** Select the normal input buffer for the RxDq pin and the normal output mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

#### UART mode connection diagram (during communication at same potential)



#### UART mode bit width (during communication at same potential) (reference)



**Remark 1.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 5, 14)

**Remark 2.**  $f_{\text{MCK}}$ : Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,

n: Channel number (mn = 00 to 03, 10 to 13))

**(5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EVDD0} = \text{EVDD1} \leq \text{VDD} \leq 5.5\text{ V}$ ,  $\text{VSS} = \text{EVSS0} = \text{EVSS1} = 0\text{ V}$ )****(1/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
Transfer rate		reception			
		4.0 V $\leq$ EVDD0 $\leq$ 5.5 V, 2.7 V $\leq$ V <sub>b</sub> $\leq$ 4.0 V		f <sub>MCK</sub> /12 Note 1	bps
		Theoretical value of the maximum transfer rate f <sub>MCK</sub> = f <sub>CLK</sub> Note 3		2.6	Mbps
		2.7 V $\leq$ EVDD0 < 4.0 V, 2.3 V $\leq$ V <sub>b</sub> $\leq$ 2.7 V		f <sub>MCK</sub> /12 Note 1	bps
		Theoretical value of the maximum transfer rate f <sub>MCK</sub> = f <sub>CLK</sub> Note 3		2.6	Mbps
		2.4 V $\leq$ EVDD0 < 3.3 V, 1.6 V $\leq$ V <sub>b</sub> $\leq$ 2.0 V		f <sub>MCK</sub> /12 Notes 1, 2	bps
		Theoretical value of the maximum transfer rate f <sub>MCK</sub> = f <sub>CLK</sub> Note 3		2.6	Mbps

**Note 1.** Transfer rate in the SNOOZE mode is 4800 bps only.

However, the SNOOZE mode cannot be used when FRQSEL4 = 1.

**Note 2.** The following conditions are required for low voltage interface when EVDD0 < VDD.2.4 V  $\leq$  EVDD0 < 2.7 V: MAX. 1.3 Mbps**Note 3.** The maximum operating frequencies of the CPU/peripheral hardware clock (f<sub>CLK</sub>) are:HS (high-speed main) mode: 32 MHz (2.7 V  $\leq$  VDD  $\leq$  5.5 V)16 MHz (2.4 V  $\leq$  VDD  $\leq$  5.5 V)

**Caution** Select the TTL input buffer for the RxDq pin and the N-ch open drain output (V<sub>DD</sub> tolerance (for the 30- to 52-pin products)/EVDD tolerance (for the 64- to 100-pin products)) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

**Remark 1.** V<sub>b</sub> [V]: Communication line voltage**Remark 2.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 5, 14)**Remark 3.** f<sub>MCK</sub>: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,

n: Channel number (mn = 00 to 03, 10 to 13)

**Remark 4.** UART2 cannot communicate at different potential when bit 1 (PIOR01) of peripheral I/O redirection register 0 (PIOR0) is 1.

**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EVDD0} = \text{EVDD1} \leq \text{VDD} \leq 5.5\text{ V}$ ,  $\text{VSS} = \text{EVSS0} = \text{EVSS1} = 0\text{ V}$ )**

Parameter	Symbol	Conditions		HS (high-speed main) mode		Unit
				MIN.	MAX.	
SCKp cycle time	t <sub>KCY1</sub>	t <sub>KCY1</sub> $\geq 4/f_{\text{CLK}}$ 4.0 V $\leq \text{EVDD0} \leq 5.5\text{ V}$ , 2.7 V $\leq \text{Vb} \leq 4.0\text{ V}$ , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 k $\Omega$		600		ns
			2.7 V $\leq \text{EVDD0} < 4.0\text{ V}$ , 2.3 V $\leq \text{Vb} \leq 2.7\text{ V}$ , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 k $\Omega$	1000		ns
			2.4 V $\leq \text{EVDD0} < 3.3\text{ V}$ , 1.6 V $\leq \text{Vb} \leq 2.0\text{ V}$ , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 k $\Omega$	2300		ns
SCKp high-level width	t <sub>KH1</sub>	4.0 V $\leq \text{EVDD0} \leq 5.5\text{ V}$ , 2.7 V $\leq \text{Vb} \leq 4.0\text{ V}$ , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 k $\Omega$		t <sub>KCY1</sub> /2 - 150		ns
		2.7 V $\leq \text{EVDD0} < 4.0\text{ V}$ , 2.3 V $\leq \text{Vb} \leq 2.7\text{ V}$ , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 k $\Omega$		t <sub>KCY1</sub> /2 - 340		ns
		2.4 V $\leq \text{EVDD0} < 3.3\text{ V}$ , 1.6 V $\leq \text{Vb} \leq 2.0\text{ V}$ , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 k $\Omega$		t <sub>KCY1</sub> /2 - 916		ns
SCKp low-level width	t <sub>KL1</sub>	4.0 V $\leq \text{EVDD0} \leq 5.5\text{ V}$ , 2.7 V $\leq \text{Vb} \leq 4.0\text{ V}$ , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 k $\Omega$		t <sub>KCY1</sub> /2 - 24		ns
		2.7 V $\leq \text{EVDD0} < 4.0\text{ V}$ , 2.3 V $\leq \text{Vb} \leq 2.7\text{ V}$ , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 k $\Omega$		t <sub>KCY1</sub> /2 - 36		ns
		2.4 V $\leq \text{EVDD0} < 3.3\text{ V}$ , 1.6 V $\leq \text{Vb} \leq 2.0\text{ V}$ , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 k $\Omega$		t <sub>KCY1</sub> /2 - 100		ns

**Caution** Select the TTL input buffer for the SIp pin and the N-ch open drain output (V<sub>DD</sub> tolerance (for the 30- to 52-pin products)/EV<sub>DD</sub> tolerance (for the 64- to 100-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

(Remarks are listed two pages after the next page.)

**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EVDD0} = \text{EVDD1} \leq \text{VDD} \leq 5.5\text{ V}$ ,  $\text{VSS} = \text{EVSS0} = \text{EVSS1} = 0\text{ V}$ )****(2/3)**

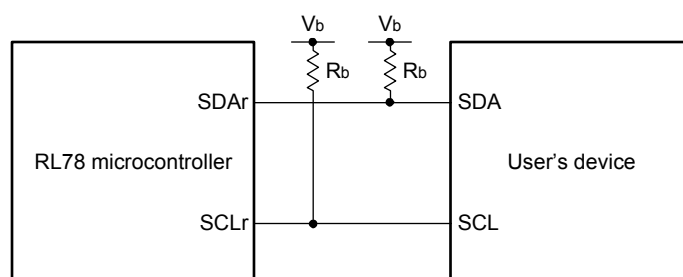
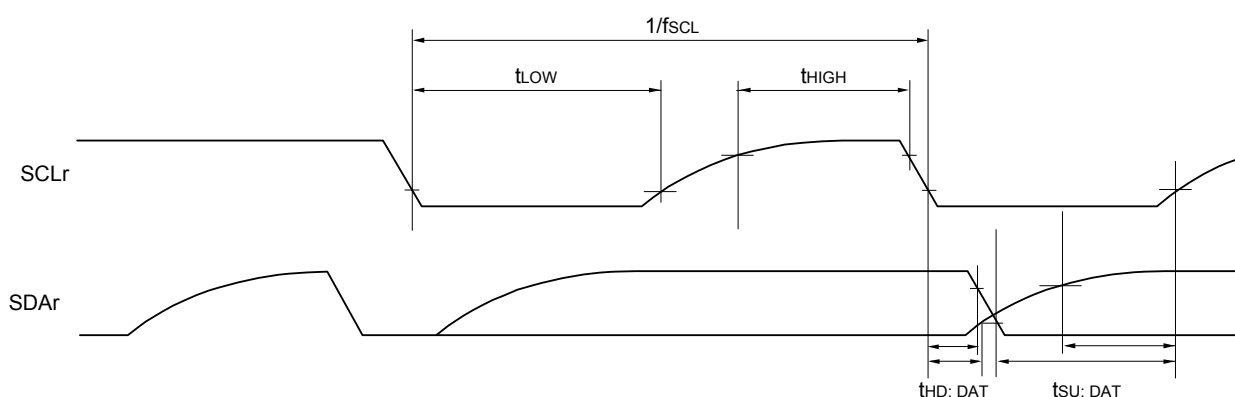
Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
Slp setup time (to SCKp $\uparrow$ ) <sup>Note</sup>	tsik1	$4.0\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq \text{Vb} \leq 4.0\text{ V}$ , $\text{Cb} = 30\text{ pF}$ , $\text{Rb} = 1.4\text{ k}\Omega$	162		ns
		$2.7\text{ V} \leq \text{EVDD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq \text{Vb} \leq 2.7\text{ V}$ , $\text{Cb} = 30\text{ pF}$ , $\text{Rb} = 2.7\text{ k}\Omega$	354		ns
		$2.4\text{ V} \leq \text{EVDD0} < 3.3\text{ V}$ , $1.6\text{ V} \leq \text{Vb} \leq 2.0\text{ V}$ , $\text{Cb} = 30\text{ pF}$ , $\text{Rb} = 5.5\text{ k}\Omega$	958		ns
Slp hold time (from SCKp $\uparrow$ ) <sup>Note</sup>	tkS11	$4.0\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq \text{Vb} \leq 4.0\text{ V}$ , $\text{Cb} = 30\text{ pF}$ , $\text{Rb} = 1.4\text{ k}\Omega$	38		ns
		$2.7\text{ V} \leq \text{EVDD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq \text{Vb} \leq 2.7\text{ V}$ , $\text{Cb} = 30\text{ pF}$ , $\text{Rb} = 2.7\text{ k}\Omega$	38		ns
		$2.4\text{ V} \leq \text{EVDD0} < 3.3\text{ V}$ , $1.6\text{ V} \leq \text{Vb} \leq 2.0\text{ V}$ , $\text{Cb} = 30\text{ pF}$ , $\text{Rb} = 5.5\text{ k}\Omega$	38		ns
Delay time from SCKp $\downarrow$ to SOp output <sup>Note</sup>	tkSO1	$4.0\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq \text{Vb} \leq 4.0\text{ V}$ , $\text{Cb} = 30\text{ pF}$ , $\text{Rb} = 1.4\text{ k}\Omega$		200	ns
		$2.7\text{ V} \leq \text{EVDD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq \text{Vb} \leq 2.7\text{ V}$ , $\text{Cb} = 30\text{ pF}$ , $\text{Rb} = 2.7\text{ k}\Omega$		390	ns
		$2.4\text{ V} \leq \text{EVDD0} < 3.3\text{ V}$ , $1.6\text{ V} \leq \text{Vb} \leq 2.0\text{ V}$ , $\text{Cb} = 30\text{ pF}$ , $\text{Rb} = 5.5\text{ k}\Omega$		966	ns

**Note** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.

**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output ( $\text{VDD}$  tolerance (for the 30- to 52-pin products)/ $\text{EVDD}$  tolerance (for the 64- to 100-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For  $\text{V}_{IH}$  and  $\text{V}_{IL}$ , see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the page after the next page.)



**Simplified I<sup>2</sup>C mode connection diagram (during communication at different potential)****Simplified I<sup>2</sup>C mode serial transfer timing (during communication at different potential)**

**Remark 1.**  $R_b[\Omega]$ : Communication line (SDAr, SCLr) pull-up resistance,  $C_b[F]$ : Communication line (SDAr, SCLr) load capacitance,  $V_b[V]$ : Communication line voltage

**Remark 2.**  $r$ : IIC number ( $r = 00, 01, 10, 11, 20, 30, 31$ ),  $g$ : PIM, POM number ( $g = 0, 1, 3$  to  $5, 14$ )

**Remark 3.**  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).  $m$ : Unit number ( $m = 0, 1$ ),  
 $n$ : Channel number ( $n = 0, 2$ ),  $mn = 00, 01, 02, 10, 12, 13$ )

### 3.6 Analog Characteristics

#### 3.6.1 A/D converter characteristics

##### Classification of A/D converter characteristics

Reference Voltage	Reference voltage (+) = $AV_{REFP}$ Reference voltage (-) = $AV_{REFM}$	Reference voltage (+) = $V_{DD}$ Reference voltage (-) = $V_{SS}$	Reference voltage (+) = $V_{BGR}$ Reference voltage (-) = $AV_{REFM}$
Input channel			
ANI0 to ANI14	Refer to 3.6.1 (1).	Refer to 3.6.1 (3).	Refer to 3.6.1 (4).
ANI16 to ANI20	Refer to 3.6.1 (2).		
Internal reference voltage Temperature sensor output voltage	Refer to 3.6.1 (1).		—

(1) When reference voltage (+) =  $AV_{REFP}/ANI0$  ( $ADREFP1 = 0$ ,  $ADREFP0 = 1$ ), reference voltage (-) =  $AV_{REFM}/ANI1$  ( $ADREFM = 1$ ), target pin: ANI2 to ANI14, internal reference voltage, and temperature sensor output voltage

( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq AV_{REFP} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ , Reference voltage (+) =  $AV_{REFP}$ ,  
Reference voltage (-) =  $AV_{REFM} = 0\text{ V}$ )

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	RES		8		10	bit
Overall error Note 1	AINL	10-bit resolution $AV_{REFP} = V_{DD}$ Note 3	$2.4\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$	1.2	$\pm 3.5$	LSB
Conversion time	$t_{CONV}$	10-bit resolution Target pin: ANI2 to ANI14	$3.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	2.125	39	$\mu\text{s}$
			$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	3.1875	39	$\mu\text{s}$
			$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	17	39	$\mu\text{s}$
		10-bit resolution Target pin: Internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode)	$3.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	2.375	39	$\mu\text{s}$
			$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	3.5625	39	$\mu\text{s}$
			$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	17	39	$\mu\text{s}$
Zero-scale error Notes 1, 2	EZS	10-bit resolution $AV_{REFP} = V_{DD}$ Note 3	$2.4\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$		$\pm 0.25$	%FSR
Full-scale error Notes 1, 2	EFS	10-bit resolution $AV_{REFP} = V_{DD}$ Note 3	$2.4\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$		$\pm 0.25$	%FSR
Integral linearity error Note 1	ILE	10-bit resolution $AV_{REFP} = V_{DD}$ Note 3	$2.4\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$		$\pm 2.5$	LSB
Differential linearity error Note 1	DLE	10-bit resolution $AV_{REFP} = V_{DD}$ Note 3	$2.4\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$		$\pm 1.5$	LSB
Analog input voltage	$V_{AIN}$	ANI2 to ANI14	0		$AV_{REFP}$	V
		Internal reference voltage output ( $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , HS (high-speed main) mode)	$V_{BGR}$ Note 4			V
		Temperature sensor output voltage ( $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , HS (high-speed main) mode)	$V_{TMPS25}$ Note 4			V

**Note 1.** Excludes quantization error ( $\pm 1/2$  LSB).

**Note 2.** This value is indicated as a ratio (%FSR) to the full-scale value.

**Note 3.** When  $AV_{REFP} < V_{DD}$ , the MAX. values are as follows.

Overall error: Add  $\pm 1.0$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .

Zero-scale error/Full-scale error: Add  $\pm 0.05\%$ FSR to the MAX. value when  $AV_{REFP} = V_{DD}$ .

Integral linearity error/ Differential linearity error: Add  $\pm 0.5$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .

**Note 4.** Refer to 3.6.2 Temperature sensor characteristics/internal reference voltage characteristic.

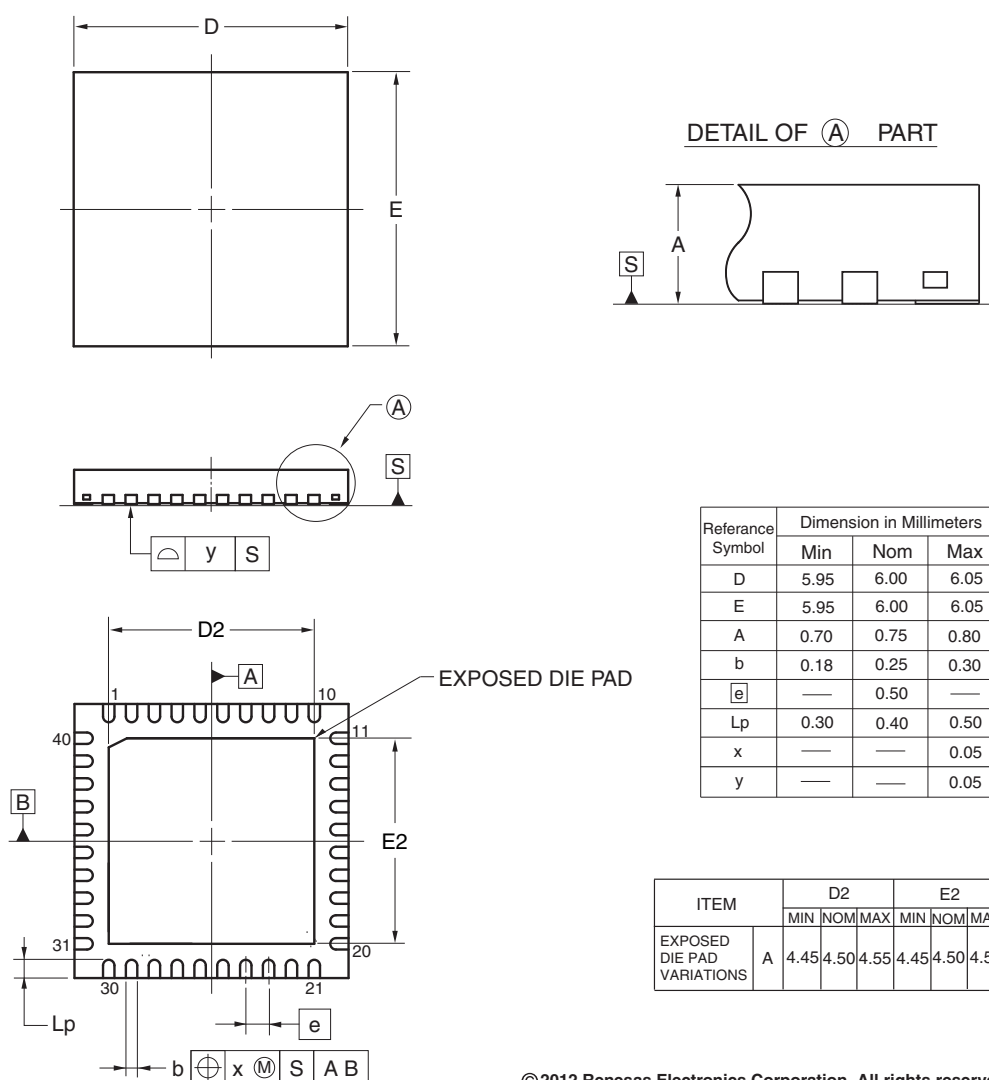
#### 4.4 40-pin products

R5F104EAANA, R5F104ECANA, R5F104EDANA, R5F104EEANA, R5F104EFANA, R5F104EGANA, R5F104EHANA

R5F104EADNA, R5F104ECDNA, R5F104EDDNA, R5F104EEDNA, R5F104EFDNA, R5F104EGDNA, R5F104EHDNA

R5F104EAGNA, R5F104ECGNA, R5F104EDGNA, R5F104EEGNA, R5F104EFGNA, R5F104EGGNA, R5F104EHGNA

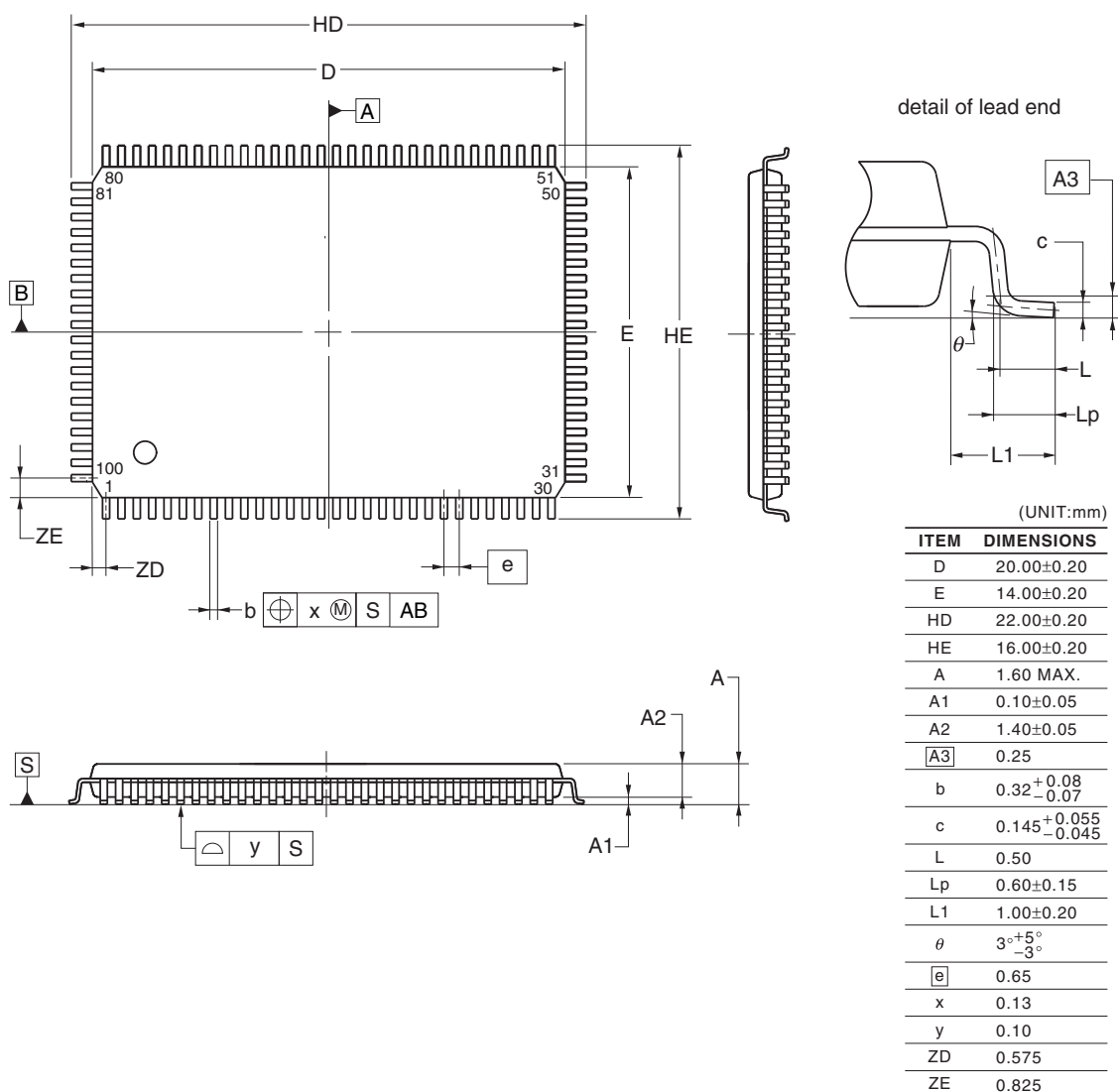
JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-HWQFN40-6x6-0.50	PWQN0040KC-A	P40K8-50-4B4-4	0.09



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R5F104PFAFA, R5F104PGAFA, R5F104PHAFA, R5F104PJFAFA  
 R5F104PFDFA, R5F104PGDFA, R5F104PHDFA, R5F104PJDFA  
 R5F104PFGFA, R5F104PGGFA, R5F104PHGFA, R5F104PJGFA  
 R5F104PKAFA, R5F104PLAFA  
 R5F104PKGFA, R5F104PLGFA

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LQFP100-14x20-0.65	PLQP0100JC-A	P100GF-65-GBN-1	0.92



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REVISION HISTORY	RL78/G14 Datasheet
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Rev.	Date	Description	
		Page	Summary
2.00	Oct 25, 2013	112 to 169 171 to 187	Addition of CHAPTER 3 ELECTRICAL SPECIFICATIONS Modification of 4.1 30-pin products to 4.10 100-pin products
3.00	Feb 07, 2014	All 1 2 3  6 to 8 15, 16 17 18, 19 20 21, 22 35, 37, 39, 41, 43, 45, 47 42, 43 46, 47  65 to 68 118 137 to 140 180 189, 190 191 193 to 195 198, 199 201, 202	Addition of products with maximum 512 KB flash ROM and 48 KB RAM Modification of 1.1 Features Modification of ROM, RAM capacities and addition of note 3 Modification of Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14 Addition of part number Modification of 1.3.6 48-pin products Modification of 1.3.7 52-pin products Modification of 1.3.8 64-pin products Modification of 1.3.9 80-pin products Modification of 1.3.10 100-pin products Modification of operating ambient temperature in 1.6 Outline of Functions Addition of table of 48-pin, 52-pin, 64-pin products (code flash memory 384 KB to 512 KB) Addition of table of 80-pin, 100-pin products (code flash memory 384 KB to 512 KB) Addition of (3) Flash ROM: 384 to 512 KB of 48- to 100-pin products Modification of 2.7 Data Memory Retention Characteristics Addition of (3) Flash ROM: 384 to 512 KB of 48- to 100-pin products Modification of 3.7 Data Memory Retention Characteristics Addition and modification of 4.6 48-pin products Modification of 4.7 52-pin products Addition and modification of 4.8 64-pin products Addition and modification of 4.9 80-pin products Addition and modification of 4.10 100-pin products
3.20	Jan 05, 2015	p.2  p.6  p.6 to 8 p.17 p.36, 39, 42, 45, 48, 50, 52 p.46, 48 p.47 p.62, 64, 66, 68, 70, 72	Deletion of R5F104JK and R5F104JL from the list of ROM and RAM capacities and modification of note Deletion of ordering part numbers of R5F104JK and R5F104JL from 52-pin plastic LQFP package in 1.2 Ordering Information Deletion of note 2 in 1.2 Ordering Information Deletion of note 2 in 1.3.7 52-pin products Modification of description in 1.6 Outline of Functions  Deletion of description of 52-pin in 1.6 Outline of Functions Modification of note of 1.6 Outline of Functions Modification of specifications in 2.3.2 Supply current characteristics